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Excitons in a single quantum well wire: optical response and application to the gratings

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Abstract: Variational envelope function of an exciton in a single quantum well wire (SQWW) is described in the framework of the effective mass approximation for two-band model. The SQWW considered has thickness values : $L_z < a_B$, along the growth axis of the sample, and $L_x > 3a_B$ for the lateral dimension (where a_B is the Bohr radius). Exciton polarizations and optical response for SQWW and for a grating of QWWs are given. The role of the local fields on the optical response of these two different superstructures is pointed out.

1. Introduction: The improvement in microstructure fabrication allows to study the exciton behaviour in single quantum well wires (SQWWs) as a function of lateral dimension. The techniques widely used to define QWWs (electron-beam lithography or optical holography followed by dry etching) give 1D-structures that show, along the lateral dimension, perfect confinement of the exciton and large dead-layer effect ⁽¹⁾. In the present paper we study the local field effects due to the grating periodicity in rather large QWWs. This study is performed comparing optical response in a SQWW and in a grating of QWWs. In Section 2 the exciton properties in a SQWW of GaAs/GaAlAs are discussed in the framework of two band model and perfect confinement of the exciton. In Section 3 optical response of a single QWW and of a grating of QWW are computed and the local field effects for these two superstructures are briefly discussed. Conclusions are given in Section 4.

2. Exciton properties in a SQWW: Let us consider a SQWW where y is the axis of symmetry of the wire and $L_z < a_B$ is the dimension along the growth axis, while $L_x > 3a_B$ is the lateral dimension, and a_B is the Bohr radius.

Modelling the Wannier exciton as perfectly confined along x -axis, and neglecting the contribution of the center-of-mass motion along y -axis, the exciton Hamiltonian (with $\hbar=1$) is:

$$H_{ex} = -\frac{1}{2M} \left[\frac{\partial^2}{\partial X^2} + \frac{\partial^2}{\partial Z^2} \right] - \frac{\nabla_r^2}{2\mu} - \frac{1}{\epsilon_0 r} + V_e(z_e) + V_h(z_h) \quad (1)$$

where μ and M are respectively the reduced and the total exciton masses and $V_e(z_e)$ and $V_h(z_h)$ are the confinement potentials for electron and hole, along z -axis. A well suited trial envelope function for an exciton in a SQWW is:

$$\phi_{ex}(r, X, Z) = N_{mnl} Q_m(x, X) R_n(z_e, z_h) \phi_l(r) \quad (2)$$

where $r = r_e - r_h$ is the relative vector distance between e-h and (X, Y, Z) are the coordinates of the center-of-mass. N_{mnl} is the normalization constant in the (r, X, Z) space, $\phi_l(r)$ is the hydrogenic wave function (for $l=1$ is: $\exp[-\alpha r]$), $Q_m(x, X)$ is the D'Andrea-Del Sole ⁽²⁾ confinement function ($L_x > 3a_B$), and $R_n(z_e, z_h)$ is a product of two subbands respectively for electron and hole.

In order to minimize the first momentum of the total Hamiltonian of eq.(1), as a function of two variational parameters, namely: $1/\alpha$ the exciton radius embodied into the hydrogenic wave function

$\phi_l(r;\alpha)$, and $1/P$ the exciton dead-layer that appears in the confinement function $Q_m(x,X;P)$ (2), we proceed in two steps.

The first step consists in the minimization of the Hamiltonian matrix element,

$$\langle \phi_{ex} | H_{ex}^0 | \phi_{ex} \rangle = N_{mnl}^2 \langle Q_m(x,X;P) \phi_l(r;\alpha) | W(z) \left[-\frac{1}{2M} \frac{\partial^2}{\partial X^2} - \frac{\nabla_r^2}{2\mu} - \frac{1}{\epsilon_0 r} \right] | Q_m(x,X;P) \phi_l(r;\alpha) \rangle$$

= minimum . (3)

as a function of variational parameter P taking $\alpha=1/a_B$ =constant . Note that the integrand is very similar to that used in the single quantum well (SQW) (3) except for the weight-function $W(z)=\int dZ |R_n(z,Z)|^2$ not present in that case. Moreover, integrating the matrix element of eq.(3) on the z-relative coordinate, we obtain a 2D-averaged Coulomb potential (4).

The second step consists in the minimization of the total exciton Hamiltonian as function of α -parameter (for P =constant),

$$\langle \phi_{ex} | H_{ex} | \phi_{ex} \rangle = \langle \phi_{ex} | H_{ex}^0 | \phi_{ex} \rangle - \frac{1}{\mu} N_{mnl}^2 \langle R_n(z,Z) \phi_l(r;\alpha) | w(x,P) | \frac{\partial R_n}{\partial z} \frac{\partial \phi_l}{\partial z} \rangle, \quad (4)$$

where $w(x,P)$ is $w(x,P)=\int dX |Q_m(x,X;P)|^2$.

The general minimum is obtained by a self-consistent procedure. The convergence of the process is usually very fast and the minimum is reached after a few cycles of computation.

The exciton dipole moment in SQWW per unit of length is:

$$f_0/L_y = \mu_{cv} N_{mnl} \left| \int dX dZ Q_m(x=0,X) R_n(z=0,Z) \phi_l(r=0) \right| \quad (5)$$

The physical parameters used for the calculations in GaAs/GaAlAs system are: $\epsilon_0=12.6$, $M=0.3m$, $Ryd.=4.2meV$, $4\pi\alpha=0.0022$ and $E_{TO}=1.515eV$. In fig.1 is shown the exciton dipole moment f_0/L_y for all the range of L_z and for two different values of the lateral dimension L_x (2). For large value range of L_z ($L_z > a_B$) we use D'Andrea-Del Sole confinement function (3) also for z-motion of exciton.

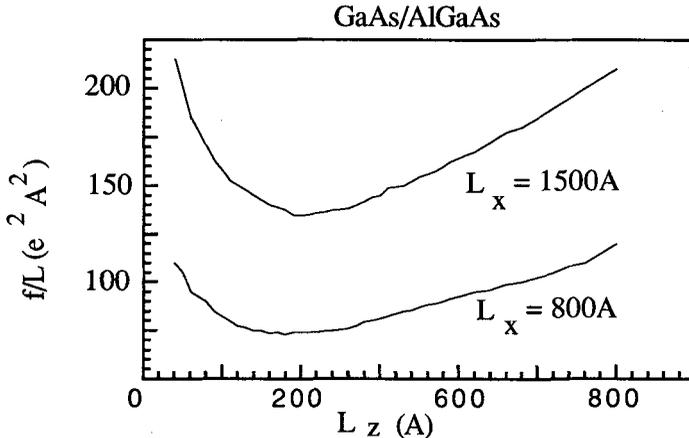


Fig.1 Exciton dipole moment per unit of length in a single quantum well wire.

3.Optical Response: Now, let us consider a SWW embedded in a semi-infinite solid with the surface in the plane (x,y) and with the static dielectric constant ϵ_0 . Taking the incident electric field with the momentum $\mathbf{K}=(K_x,0,K_z)$, the Maxwell equations decouple in S and P polarizations and it can be exactly solved, see Refs.(2,5). We will neglect the stationary polariton and consider only the optical

response of the resonant modes ⁽⁶⁾. The Fourier transformed polarizability for SQWW (for $n=0$ and $l=1$) is:

$$4\pi P(k_x, Z) = (\epsilon_0 - 1) E(k_x, Z) + \sum_m N_m^2 \frac{S_0}{E_m - \hbar\omega} Q_m^*(-k_x) R^*(Z) \int dk'_x Q_m(-k'_x) \int dZ' R(Z') E(k'_x, Z'), \quad (6)$$

where S_0 embodies the valence-conduction dipole moment transition.

Let us consider a SQWW of dimensions $L_x=1500\text{\AA}$ and $L_z=100\text{\AA}$. Note that we will use in the calculation an unrealistically low Γ -value ($=0.03\text{meV}$) in order to point out rather small effects in the theoretical spectra.

The reflectivity for S-polarized light is shown in fig.2a for incident angle: $\phi_i=30^\circ$. This result is obtained normalizing the data in a small angle around the reflection condition. The two peaks are due to the exciton center-of-mass quantization ($n=1$ and $n=3$) along the x-axis in the wire. In fig.2b we compute for the same system the reflectivity with reflection angle ϕ_r different from the incident one, namely: $\omega/c \sin(\phi_r) = \omega/c \sin(\phi_i) \pm 2\pi/(10L_x)$. The intensity of the peaks decreases respect to the reflection condition $\phi_r = \phi_i$, in fact, the term $2\pi/(10L_x)$ is of the same order of magnitude than the light impulse. Moreover, reflection peaks at exciton energies $n=1,2$ for $q_x \pm 2\pi/(10L_x)$ shows different intensity values (see fig.2b where R_+ is the solid line, R_- dashed line and $R_+ > R_-$).

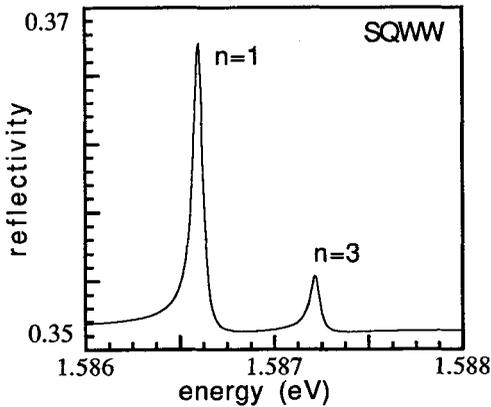


Fig.2a- Reflectivity for SQWW ($\phi_r = \phi_i$)

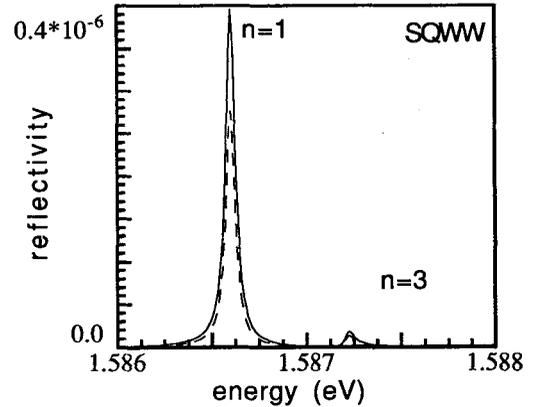


Fig.2b- Reflectivity for SQWW ($\phi_r \neq \phi_i$)

Now, let us consider a grating of QWWs embedded in a semi-infinite solid of dielectric constant ϵ_0 ⁽²⁾. The exciton polarizability is,

$$4\pi P(k_x, Z) = (\epsilon_0 - 1) E(k_x, Z) + \frac{1}{d} \sum_m N_m^2 \frac{S_0}{E_m - \hbar\omega} Q_m^*(-k_x) R^*(Z) \sum_G Q_m(-k_x + G) \int dZ' R(Z') E(k_x + G, Z'), \quad (7)$$

where d is the distance between adjacent QWWs and $G = 2\pi/d$ is the reciprocal lattice vector.

In fig. 3a is shown the reflectivity ($G=0$) for $q_x = \omega/c \sin(\phi_i)$, where $\phi_i=30^\circ$ is the incident angle, and for two different distances between adjacent wires, namely: $d=5000\text{\AA}$ and $d=1600\text{\AA}$. Obviously, in the limit $d \rightarrow \infty$ the intensity of the peaks decreases and it could converge to the static bulk reflectivity for a single spot G and to the SQWW reflectivity of fig.2a if integrated on the chosen small angle. In fig.3b is computed the reflectivity for impulse parallel to the surface respectively: $q_x = \omega/c \sin(\phi_i) \pm G$. Note that in this case we obtain a response qualitatively different from the case $G=0$, in fact, due to

different selection rules for reflection and out of reflection cases, also odd states ($n=2$) appears in the spectra. Moreover, for asymmetric conditions ($\phi_i \neq 0$) there is a strong redistribution of the intensities among the exciton peaks ($n=1,2,3$) and reflectivities are: $R_+ < R_-$.

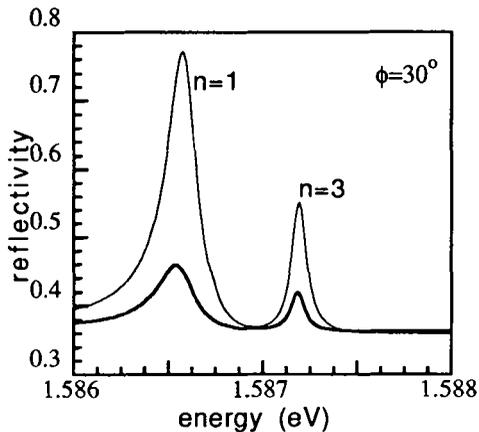


Fig.3a - Reflectivities of a grating of QWWs for $G=0$ and $d: 1600\text{\AA}$ (thin solid line) and 5000\AA (thick solid line).

Quantitative comparison with the reflectivity in SQWW of fig.2a is not easy, due to the different normalization conditions in a grating and in a single wire. The study of the reflectivities ratio R_+/R_- between light reflected at $q_x \pm G$ is a finger print of the local field effects. Finally, preliminary results for QWWs with rather large lateral thickness ($L_x = 10a_B$) give non-negligible optical response for out of reflection condition in these superstructures.

4.Conclusions: In conclusion, we present a framework for computing optical response in QWWs in all the range of lateral dimensions. Preliminary results seem to allow a compared study of the local field effects on the optical response from SQWW to the periodic grating in QWWs with rather large lateral dimension.

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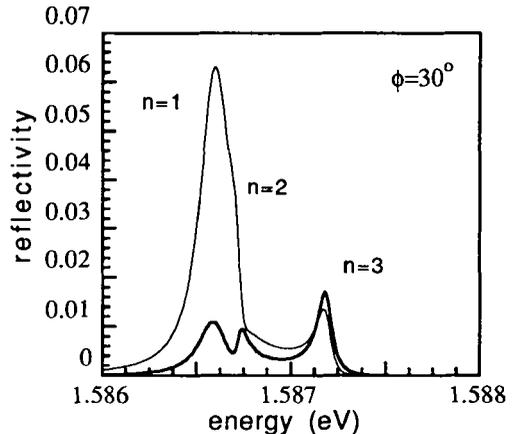


Fig.3b - Reflectivities of a grating of QWWs for $G=+2\pi/d$ (thick solid line) and for $G=-2\pi/d$ (thin solid line).